

120MHz BANDWIDTH MOS INPUT SINGLE OPERATIONAL AMPLIFIER

TSH11

- VERY LOW INPUT CURRENT : 2pA typ
- GAIN BANDWIDTH PRODUCT : 120MHz
- UNITY GAIN STABLE
- SLEW RATE : 150V/µs
- STANDARD PIN OUT

DESCRIPTION

The TSH11 is a low cost wide bandwidth single operational amplifier featuring extremely low input current of 2pA typ. Other features as unity gain stability, fast settling time and high linearity make it suitable for many applications requiring speed and very high input impedance as photo cell amplifier, high input impedance buffer, Fet probe, high speed precision integrator, sample and hold circuit.

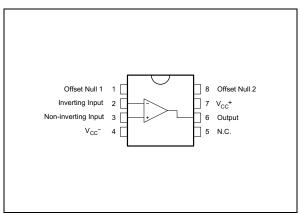
ORDER CODE

Part Number	Temperature Range	Package	
Fart Number	Temperature Kange	D	
TSH11I	-40°C, +125°C	•	

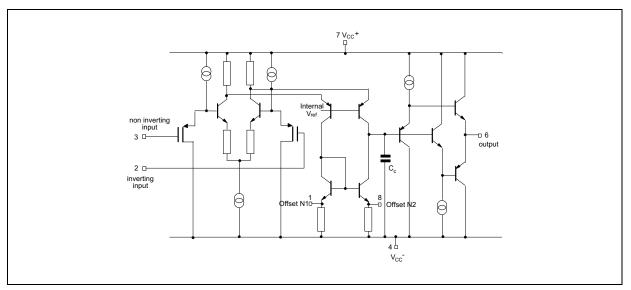
D = Small Outline Package (SO) - also available in Tape & Reel (DT)



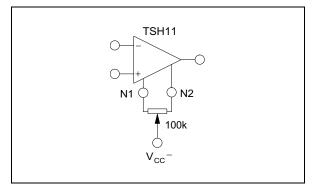
PIN CONNECTIONS (top view)



SCHEMATIC DIAGRAM



INPUT OFFSET VOLTAGE NULL CIRCUIT



MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{cc}	Supply Voltage	±7	V
V _{id}	Differential Input Voltage	±5	V
Vi	Input Voltage	±5	V
l _{in}	Current On Offset Null Pins	±20	V
T _{oper}	Operating Free-Air Temperature range	-40 to +125	°C

OPERATING CONDITIONS

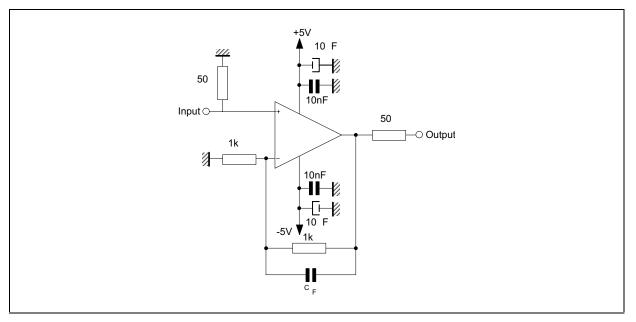
Symbol	Parameter	Value	Unit
V _{cc}	Supply Voltage	±3 to ±6	V
V _{ic}	Common Mode Input Voltage Range	V_{CC}^{-} to V_{CC}^{+} -3	V

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Min.	Тур.	Max.	Unit
V _{io}	Input Offset Voltage		3	15	mV
DV _{io}	Input Offset Voltage Drift $T_{min} \le T_{amb} \le T_{max}$.		20		μV/°C
l _{ib}	Input Bias Current		2	300	pА
l _{io}	Input Offset Current		2	200	pА
I _{cc}	Supply Current, no load $V_{CC} = \pm 5V$		20	40	mA
Avd	Large Signal Voltage Gain $Vo = \pm 2.5V$ $R_L = 100\Omega$	200	800		V/V
V _{icm}	Input Common Mode Voltage Range	-5 to +2	-5.5 to +2.5		V
CMR	Common-mode Rejection Ratio V _{ic} = V _{icm min.}	55	95		dB
SVR	Supply Voltage Rejection Ratio $V_{CC} = \pm 5V$ to $\pm 3V$	45	70		dB
Vo	Output Voltage $R_L = 100\Omega$	±2.5	+3.5 -3.7		V
Ι _ο	Output Short Circuit Current Vid = $\pm 1V$, Vo = 0V		±70		mA
GBP	Gain Bandwidth Product $A_{VCL} = 100$, $R_L = 100\Omega$, $f = 7.5MHz$		120		MHz
SR	Slew Rate $V_{in} = \pm 2V$, $A_{VCL} = 1$, $R_L = 100\Omega$		150		V/µs
e _n	Equivalent Input Voltage Noise f = 1MHz		20		nV/√Hz
φm	Phase Margin $A_{VM} = 1$, $R_L = 100\Omega$, $C_L = 15pF$		40		Degrees

 $V_{CC} = \pm 5V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

EVALUATION CIRCUIT



PRINTED CIRCUIT LAYOUT

As for any high frequency device, a few rules must be observed when designing the PCB to get the best performances from this high speed op amp.

From the most to the least important points :

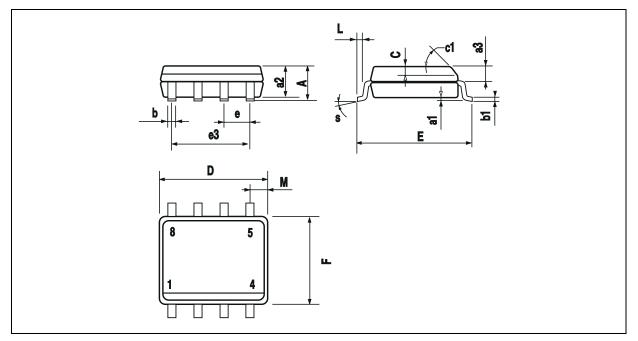
- Each power supply lead has to be bypassed to ground with a 10nF ceramic capacitor very close to the device and a 10μF tantalum capacitor.
- To provide low inductance and low resistance common return, use a ground plane or common point return for power and signal.
- All leads must be wide and as short as possible especially for op amp inputs. This is in

order to decrease parasitic capacitance and inductance.

- Use small resistor values to decrease time constant with parasitic capacitance.
- □ Choose component sizes as small as possible (SMD).
- On output, decrease capacitor load so as to avoid circuit stability being degraded which may cause oscillation. You can also add a serial resistor in order to minimise its influence.
- □ One can add in parallel with feedback resistor a few pF ceramic capacitor C_F adjusted to optimize the settling time.

PACKAGE MECHANICAL DATA

8 PINS - PLASTIC MICROPACKAGE (SO)



Dim.	Millimeters		Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
С	0.25		0.5	0.010		0.020
c1			45°	(typ.)		•
D	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
е		1.27			0.050	
e3		3.81			0.150	
F	3.8		4.0	0.150		0.157
L	0.4		1.27	0.016		0.050
М			0.6			0.024
S	8° (max.)					

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